

Vishay Siliconix

P-Channel 100 V (D-S) MOSFET

DESCRIPTION

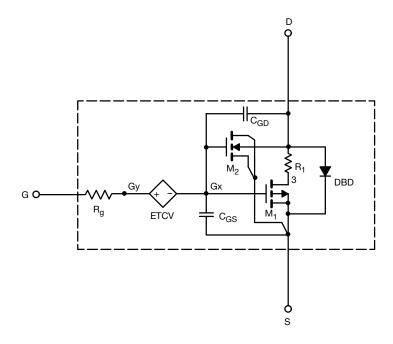
The attached SPICE model describes the typical electrical characteristics of the p-channel vertical DMOS. The sub-circuit model is extracted and optimized over the -55 $^{\circ}\text{C}$ to +125 $^{\circ}\text{C}$ temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{\rm gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- P-Channel Vertical DMOS
- Macro Model (Sub-circuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the -55 °C to +125 °C Temperature Range
- · Model the Gate Charge

SUBCIRCUIT MODEL SCHEMATIC



Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	2	-	V
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = -10 \text{ V}, I_D = -20 \text{ A}$	0.0162	0.0165	Ω
		$V_{GS} = -4.5 \text{ V}, I_D = -15 \text{ A}$	0.023	0.023	
Forward Transconductance ^a	9 _{fs}	V _{DS} = -15 V, I _D = -20 A	37	34	S
Diode Forward Voltage	V_{SD}	I _S = -6.2 A	-0.78	-0.81	V
Dynamic ^b					
Input Capacitance	C _{iss}	V _{DS} = -50 V, V _{GS} = 0 V, f = 1 MHz	3610	3395	pF
Output Capacitance	Coss		914	910	
Reverse Transfer Capacitance	C _{rss}		110	55	
Total Gate Charge	Qg	$V_{DS} = -50 \text{ V}, V_{GS} = -10 \text{ V}, I_D = -20 \text{ A}$	58	58	- nC
		$V_{DS} = -50 \text{ V}, V_{GS} = -10 \text{ V}, I_{D} = -20 \text{ A}$	30	26.5	
Gate-Source Charge	Q _{gs}		12.9	12.9	
Gate-Drain Charge	Q _{gd}		10.2	10.2	

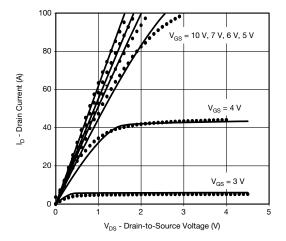
Notes

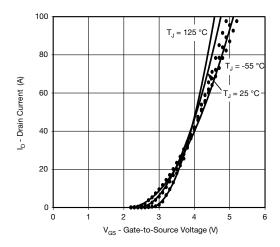
- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

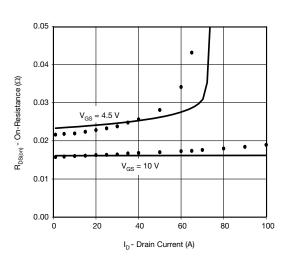
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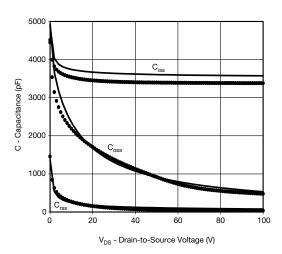
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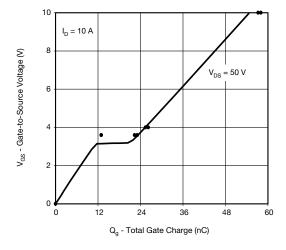
COMPARISON OF MODEL WITH MEASURED DATA (T_J = 25 °C, unless otherwise noted)

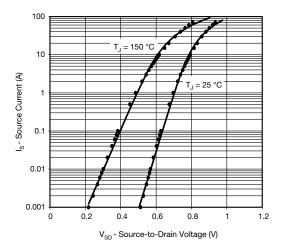












Note

Dots and squares represent measured data.
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